FEB 2 8 2005

551 Fifth Avenue, New York, NY 10176 phone 212.687.2770 fax 212.972.5487 www.cplplaw.com

From:

Teodor J. Holmberg

Pages:

8 (including this page)

Date: February 28, 2005

Our File: 5089-2PUS/CIP

Please deliver to:

Recipient:

Examiner NASSER, Robert L

**ART UNIT 3736** 

Company:

U.S. Patent & Trademark Office

Fax No.:

703-872-9302

☐ Confirmation Will Follow

☑ Confirmation Will Not Follow

Notes/Comments:

## **SUBMISSION** U.S. PAT. APP. SER. No. 09/711,462

Contents:

7 pages of documentation

This transmission may contain information which is privileged, constitutes attorney work product, or is otherwise protected from disclosure. Its contents are confidential and intended for the addressee only, and must not be used, copled, or disseminated by any person other than the addressee. The recipient is requested to notify the sender immediately of any error in transmission and to destroy any transmission not intended for the recipient. If you do not receive all pages or otherwise experience transmission difficulties, please call us at (212) 687-2770.





## MDE MEDIZINTECHNIK GmbH

### Used test equipment for the measurement:

1. Supply pulse-generator (MDE) operated by a single chip microprocessor P87C51 and with powersupply from Ulveco. The frequency, Pulselength, Pulsetrain and Amplitude could be adjusted.

Connected treatment-heads: 1 Diode-cascade (CH 363 503) / Radiation pictures per email.

- 2. IR diode type: LT4B83-81-940 / IR Diodes supplied Hemar, Manuf. By LedTech in Taiwan.
- 3. Settings: Repetion frequency of 9.9 Khz/Pulsewith: 20 usec. / Amplitude of 24 Volt. Diode coupling like schematic.
- 4. Output: Spectral schematics enclosed
- 5. Wavelength peaks: 686 nm, 942 nm, 1187 nm.
- 6. Meassurement Lab.: University in Saarbrücken Germany, Dept. of Biology, Dr. U. Warnke.
- 7. Lab. Device from Instrument Systems, Munich SP 320D connected with Photomultiplier, receiver opening @ 3,5 mm, Measurement distance approximately 5 mm.
- 8. Time: 24.09.1991

MDE Medizintechnik GmbH , P. Fach 400 , CH-8201 Schaffhausen , Fax +41-52-6431192/ email: swissmed@dplanet.ch





# MDE MEDIZINTECHNIK GmbH

Ref..: Photodynamic Simulation device (CPLP 5089-2PUS/CIP)

Normally Semiconductor diodes (LED / Light emitting diodes) is produced for continous radiation like a pocket lamp with battery ( White LED).

Normally Data depending of type / manufacturer.

Recommended supply applications:

Supply Voltage:

2,5 -4 Volt

Current / mA DC:

20 - 100 mA

The inventors method to supply the diodes:

Supply Voltage:

15 - 24 / 24 - 75 Volt

Pulsed supply:

5 - 20 usec. / 2 - 200 nsec. pulselength

Pulse repetition:

1-10 Khz

In fact the diodes is supplied similar to modern Laser diodes, where there is used fast drivers producing sharp and clear supply pulses. A monitor (Textronix) is used to control the current pulses.

A normal continous supply of the diodes would lead to production of light with one wavelength of f. examp 940 nm. Since these diodes are not producing a monochromatic light it is normal to find specification with Wavelength: 940 nm +/- 50 nm.

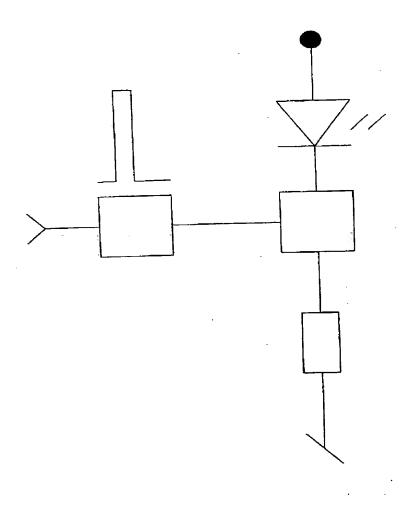
Using the demonstrated pulsed laser driving mode the diode starts to oscilate and produce light of 2 wavelengths next to the main wavelength of 940 nm.

Hereby overheating of the diodes is avoided and a better lifetime (about 10 years is proved) is achieved, combined with excellent therapy results.

It is not expected that every standard diode can be used for the above demonstrated driving method, but we have found 2-3 various brands and a special quality assorted type works excellent.

MDE Medizintechnik GmbH , P. Fach 400 , CH-8201 Schaffhausen , Fax +41-52-6431192 / email: swissmed@dptanet.ch











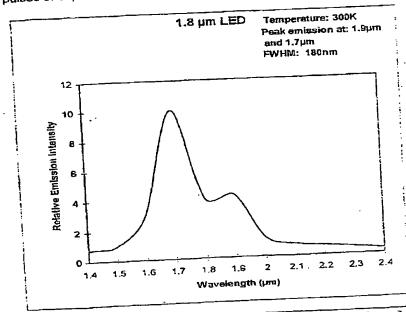


### LED18-10 Light Emitting Diode

	, 0		
	Rating	units	Conditions
Parameter	1.8	μm	300K
eak emission wavelength	0.36	μm	300K
Spectral bandwidth (FWHM)	90	μW	2.5% duty cycle
Radiant output power (@300mA):	100-200	mA	pulsed*
Operating Currents	0.8-1.0	Α	(peak current)**
	100	nS	
Rise time	2	nm/K	
Temperature drift of band	TO-18 (TO-5 apt.)		Lens / Window
Encapsulation	1	mm	
Mesa diameter	60	deg.	
Field of Vlew			

### Notes

- recommended detector is room temperature photovoltaic MCT detector model PDI-4 or TEcooled photovoltaic MCT model PDI-2TE-4; or room temperature photoconductive MCT detector PCI-4 or TE-cooled photoconductive detector model PCI-2TE-4
- DO NOT connect/disconnect the LED while the pulse generator is in operation
- the lead nearest to the tag of TO-header is the anode and marked with a red dot.
- the cathode is connected to the case
- \* square pulses of 500µsec duration and 1 KHz repetition frequency
- \*\* square pulses of 50µsec duration and 500 Hz repetition frequency





Boston Electronics Corporation, 91 Boylston Street, Brookline MA 02445 (300)347-5445 or (617)566-3821 \* fax (617)731-0935 \* boselec@boselec.com \* www.boselec.com Winfax

References: Photodynamic Simulation device (CPLP 5089-2PUS/CIP)

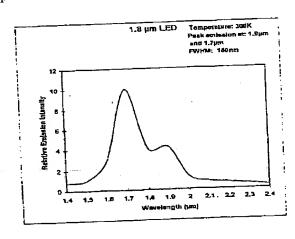
Data sheeet: Boston Electronics Corporation, 91 Boylston Street, Brookline MA02445

Component: IR Light Emitting Diode (LED 18-10)

Op. Currents: 100-200 mA

Wavelength: Infrared 1.7 um and 1.9 um

Op. Mode: Pulsed operation - 1 Khz / 500 usec.



Lecture at Laser Congress in Munich (1997) by Prof. D. Fluck University Zürich, ETH, Institute of Quatum electronics.

Stable 45 mW blue laser by frequency doubling.

Direct second-harmonic and sum frequency generation (SHG,SFG) with near infrared semicunductor laser diodes offers the possibility of robust, compact and reliable blue lasers. Efficient blue light generation at 430 nm and 490 nm by noncritical PM SHG with LD has been demonstrated for single pass, resonant and waveguide configurations. Other wavelengths in the 415 to 475 nm spectral range can be efficiently generated by making use of SFG with commercial available single-mode AigaInP, AIGaAs and InGaAs laser diodes.



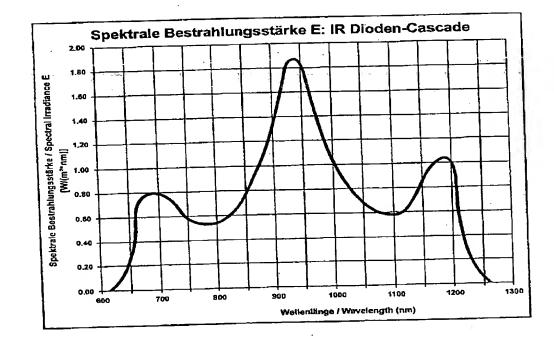








Image of hand before radiation

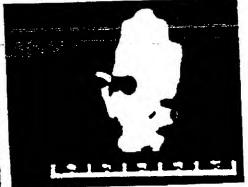


Image of hand after 30 seconds radiation with IR Diode-Cascade